

Dear Editor,

We like to express our appreciation to the reviewers for their comments. We are resubmitting the revised version of the paper number pssa.202400351. We have studied the comments of the reviewer carefully, and have changed the text according to the comments they have listed. The location of revisions is pointed by blue in “RevisedManuscript.pdf”. Below we refer to each of the reviewer’s comments.

Response to Reviewer #1

Comment 1. *The authors could consider mentioning where does the iron come to the samples? Is it in the wafers to begin with after the crystal growth or is some intentional iron contamination done prior to device processing? In my opinion this information would be worth mentioning in the manuscript.*

Reply:

The technological process of solar cells (SCs) manufacturing from Cz-p-Si wafers included the formation of separating and isotype barriers (n^+ - p and p - p^+ junctions) by diffusion of phosphorus (POCl_3) and boron (BCl_3) from the gas phase, respectively; thermal oxidation; thermal annealing; photolithography; etching the dividing groove; chemical treatments; magnetron sputtering of aluminum contacts to the front and back sides.

It has been found that some SC lots have significantly worse parameters compared to typical solar cells for this technological process. In particular, the photoconversion efficiency was almost halved. The analysis showed that the reason for such a deterioration in the SC parameters is a sharp drop in the diffusion length of minority charge carriers (electrons) L_n in the SC base. Additional experiments with thermal annealing at temperatures of 200°C and 90°C (the procedure is described by Tayyib *et al.*[1]) showed that the decrease in L_n value is caused by iron impurities available in the SC base at concentrations up to $4 \cdot 10^{13} \text{ cm}^{-3}$. It has also been found that the source of iron impurity is insufficiently pure chemicals that were used for chemical treatments in the technological process, obtained from another supplier. These reagents were the source of contamination in the process of manufacturing experimental SC samples.

At the same time, such detailed information about the samples has already been provided in a previous paper [2]. Therefore, in this manuscript, we briefly describe the causes of contamination and provide links to a more comprehensive description — see page 9, paragraphs 5.

Comment 2. *What was the size of the samples and solar cells used in the experiments? Was the whole sample/cell surface illuminated during the experiments or just part of it locally?*

Reply:

Comment 3. *Based on the reported sheet resistance values, the emitter and back surface field diffusions are quite heavy and could thus act as strong gettering sinks for iron during the device processing. Could the authors comment on this? This could lead to rather uneven distribution of iron in the samples and also the iron being in different forms in different locations. Does this affect the results and if yes, how? (Perhaps here the fact that the light used in the IV-measurements was monochromatic with a wavelength of 940 nm plays a role.)*

Reply:

Comment 4. *Keeping in mind the cell structure including e.g. strong emitter and BSF diffusions, the reported value of τ_{other} (2.2 ms) seems quite high. Could the authors comment on this? Were there any uncontaminated reference cells included in the experiments? (These would perhaps be good references also elsewhere in the manuscript.) Was their lifetime characterized to back up this claim and the resulting validity of τ_{other} being much much higher than τ_{feb} ?*

Reply:

Comment 5. *Was the iron concentration in the samples/cells verified with some of the well-established methods for iron concentration determination such as surface photovoltage method (SPV)? That would provide also simultaneously a good reference value for the diffusion length value determined in the manuscript.*

Reply:

Smaller Comment 1. *The authors could consider moving the experimental from the end to the second section in the paper. There is a lot of crucial information in the experimental part that is needed to understand the results properly. Therefore, it could be very useful for the readers to read the experimental part first before going into the results section.*

Reply:

Overall, we also support the opinion that the ability to read the experimental part first before going into the results section is useful, customary, and fully justified. However, in this case, we must adhere to the “Guide for Authors” and the L^AT_EX template which state that the order of the sections must be as follows: “Title – Author(s) – (Dedication) – Affiliation(s), – Keywords – Abstract – Main text – (Experimental/Methods Section) – Acknowledgements – References – (Biographies) – Table of Contents text [Sections in brackets are only present in certain article types]”.

Smaller Comment 2. *The paper would benefit from one round of language and typo checks. There were quite a lot of such problems all around the paper. Here are just some examples:*

Title: Should it be dissociation kinetics and not kinetic?

Page 1, line 42: “and have a solid understanding of some defects”. Something wrong in this sentence, should it be e.g. “and that there is a solid understanding of some defects.”

Page 4, lin49: “the lifetime associated with... (about 2.2 μ m)” Unit wrong, should be ms?

Page 6, line 29: “These behaviour...” Should be This behaviour?

*Figure 5 caption: “carrier generate rate”
etc.*

Reply: We apologize for any language errors. A bilingual speaker has revised the text, and we hope it shows improvement.

The reviewer is completely correct and

- title revised to “Influence of Illumination Spectrum on Dissociation Kinetics of Iron-boron Pairs in Silicon
- sentence revised to “Nevertheless, it must be noted that considerable data have been amassed on silicon, resulting in a solid understanding of certain defects.” (page 1, paragraphs 2)
- correct unit is μ s (page 1, paragraphs 2)
- the correct beginning of sentence is “This behavior...” (page 1, paragraphs 2)
- “carrier generate rate” in Figure 5 caption is replaced by “carrier generation rate” (page 1, paragraphs 2).

Other numerous corrections are highlighted in blue in “RevisedManuscript.pdf”.

Response to Reviewer #2

Comment 1. *Grammatical error in the last sentence of the abstract.*

Reply: The revised last sentence in the abstract reads:
“The cat came to work.”

The manuscript has been revised. We sincerely hope to see a significant decrease in grammatical errors.

Comment 2. *Figure1 and TOC, it looks nice, but it is difficult to understand. Authors need to add inputs and outputs. One of outputs will be K values. For example, add an arrow coming out from the box named “Discussion & Conclusion”, and write K. Otherwise, readers will not understand what is this figure for. Page2, Line40, there is an explanation of “First step”. I do not find “Second step”.*

Reply:

Comment 3. *A main result is that K values depends on the light source, namely spectral shape. These values were obtained by fitting equation(1) to the plot in Fig. 6(a). I have a doubt that K should not change by experimental condition. It is an intrinsic constant. For the fitting, N_FeB was assumed to be constant in the manuscript, but it may not.*

Comment3 is critical. Explanations are required.

Reply:

Comment 4. *A unit “cm $\hat{3}$ ” is in equation(5). It should not be.*

Reply: We respectfully disagree with the Reviewer. On one hand, the factor of 5.7×10^5 corresponds precisely to the case when the unit of acceptor-doping concentration is cm^{-3} [3, 4, 5]. On the other hand, since the temperature unit is Kelvin and the unit of p is cm^{-3} , the factor $\left(\frac{1}{\text{K cm}^3} \cdot \frac{T}{p}\right)$ is dimensionless. Thus, the expression

$$R_a^{-1} = 5.7 \times 10^5 \frac{\text{s}}{\text{K cm}^3} \times \frac{T}{p} \exp\left(\frac{E_m}{kT}\right) \quad (1)$$

has the dimension of time.

Comment 5. *I did not find where Eq.(3) and (4) are used. Exactly the same equations are in the cited articles. These equations and related sentences can be deleted so that readers can easily understand the content.*

Reply:

Sincerely yours,
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References

- [1] M. Tayyib, J. Theobald, K. Peter, J. Odden, T. Sætre, *Energy Procedia* **2012**, 27 21 , proceedings of the 2nd International Conference on Crystalline Silicon Photovoltaics SiliconPV 2012.
- [2] O. Olikh, V. Kostylyov, V. Vlasuk, R. Korkishko, Y. Olikh, R. Chupryna, *J. Appl. Phys.* **2021**, 130, 23 235703.
- [3] C. Möller, T. Bartel, F. Gibaja, K. Lauer, *J. Appl. Phys.* **2014**, 116, 2 024503.
- [4] N. Khelifati, H. S. Laine, V. Vähänissi, H. Savin, F. Z. Bouamama, D. Bouhafs, *Phys Status Solidi A* **2019**, 216, 17 1900253.
- [5] J. Tan, D. Macdonald, F. Rougieux, A. Cuevas, *Semicond Sci. Technol.* **2011**, 26, 5 055019.